

MICROCOMPUTER and PERIPHERAL LSI's

Peripheral LSI's

Type No.	Function	Maximum Ratings (Ta=25°C)	Electrical Characteristics (Ta=25°C)						
			Item	Symbol	Condition	min.	typ.	max.	Unit
MN6024	CMOS 16-Function Remote Control Circuit	V _{DD} =-0.3~+3V	"H" Level Input Voltage	V _{IH}	OSC1, OSC2	1.1		1.5	V
		V _I =-0.3~V _{DD} +0.3V	"L" Level Input Voltage	V _{IL}				0.3	V
		V _O =-0.3~V _{DD} +0.3V	Input Current	I _{IH}	KY1~KY2, V _I =1.5V	7	15		μA
		T _{opr} =-20~-+70°C	"H" Level Output Current	I _{OH1}	DT1~DT4, V _O =1.2V	-100			μA
		T _{tsg} =-40~-+100°C	"L" Level Output Current	I _{OH2}	OUT1, V _{DD} =1.1V, V _O =0.8V	-600			μA
			"L" Level Output Current	I _{OL1}	OUT1, V _{DD} =1.1V, V _O =0.3V	15			μA
		Operating Condition	"H" Level Output Current	I _{OH3}	OUT2, V _{DD} =1.1V, V _O =0.8V	-300			μA
			"L" Level Output Current	I _{OL2}	CUT2, V _{DD} =1.1V, V _O =0.3V	15			μA
		V _{DD} =1.5V	"H" Level Output Current	I _{OH4}	OSC2, OSC3, V _O =1.2V	-60			μA
		V _{SS} =0V	"L" Level Output Current	I _{OL3}	OSC2, OSC3, V _O =0.3V	60			μA
		f _{OSC} =600Hz							
		T _a =25°C							
△MN6025	CMOS Multi-Function Remote Control Circuit	V _{DD} =-0.3~+5V	Supply Current	I _{DD}	Without key input			30	μA
		V _I =-0.3~V _{DD} +0.3V	Power Consumption	P _{tot}				60	μW
		V _O =-0.3~V _{DD} +0.3V	Input Pin	V _{IH}		2.4			V
		T _{opr} =-30~-+70°C	KY1~KY7	V _{IL}				0.6	V
		T _{tsg} =-35~-+100°C	Input Current	I _I	V _I =3V	10	50	μA	
		Operating Condition	CNT OSC2 MODE	V _{IH}		2.4			V
				V _{IL}				0.6	V
		V _{DD} =3V	Output Pin	I _{OH1}	V _O =2.4V	-100			μA
		V _{SS} =0V	I _{OH2}	V _O =0.8V	-1.5				mA
		T _a =25°C	I _{OL2}	V _O =0.6V	50				μA
		OSC1	I _{OH3}	V _O =2.4V	-100				μA
			I _{OL3}	V _O =0.6V	100				μA
MN6044	CMOS Frequency Synthesizer for TV	V _{DD} =-0.3~+7V	Supply Current	I _{DD}	Without load			1	5 mA
		V _I =-0.3~+7V	Power Consumption	P _{tot}		RC=1/3667, SC=1/1023		5	25 mW
		V _O =-0.3~+7V	Input Pin	f _i		3.7			MHz
		P _D =30mW	Input Voltage Swing	V _i					V _{P-P}
		T _{opr} =-20~-+70°C	Input Current	I _I	V _i =V _{SS} ~V _{DD}			±30	μA
		T _{tsg} =-55~-+100°C	PI0~3 CI0~2 LDI	V _{IH2}		2.4		V _{DD}	V
				V _{IL2}		V _{SS}	0.8		V
		V _{DD} =5V	PIDO	I _{OH}	V _O =3V	-0.8			mA
		V _{SS} =0V	I _{OL}	V _O =2V	+0.8				mA
		T _a =-20~-+70°C	TMO	V _{OP}	I _{OH} =-100μA	3			V
				V _{OL}	I _{OL} =100μA			0.4	V
		Q1, Q0	Osc. Frequency	f _{OSC}	C ₁ =22pF, C ₀ =30±10pF	3.58			MHz
MN6047	CMOS PLL Frequency Synthesizer for FM/AM Radio	V _{DD} =-0.3~+10V	Supply Current	I _{DD}	V _{DD} =5V, T _a =25°C			3	5 mA
		V _I =-0.3~+10V	Power Consumption	P _{tot}				15	25 mW
		V _O =-0.3~+10V	"H" Level Input Voltage	V _{IH}	P0~P3, C0~C2, LD, V _{DD} =5V	2.4		V _{DD}	V
		P _D =50mW	"L" Level Input Voltage	V _{IL}		V _{SS}	0.8		V
		T _{opr} =-30~-+70°C	Input Frequency Upper Limit	f _i : max	V _{DD} =4.5~6.5V	4			MHz
		T _{tsg} =-55~-+100°C			V _{DD} =5.5~6.5V	6			MHz
		Oscillation Frequency	f _{OSC}	OSC1, OSC2		11.52			MHz
		Operating Condition	"H" Level Output Current	I _{OH}	PD	V _O =3V	-0.8		mA
			"L" Level Output Current	I _{OL}		V _O =2V	0.8		mA
MN6047	PLL Frequency Synthesizer for FM/AM Radio	V _{DD} =5V	"H" Level Output Voltage	V _{OH}	CPO, QO	V _{DD} =5V I _{OH} =-100μA	4		V
		V _{SS} =0V	"L" Level Output Voltage	V _{OL}		V _{DD} =5V I _{OL} =100μA		0.4	V
		T _a =-30~-+70°C	Input Capacitance	C _I	V _I =2V		5		pF
			Output Capacitance	C _O	V _O =2V		7		pF

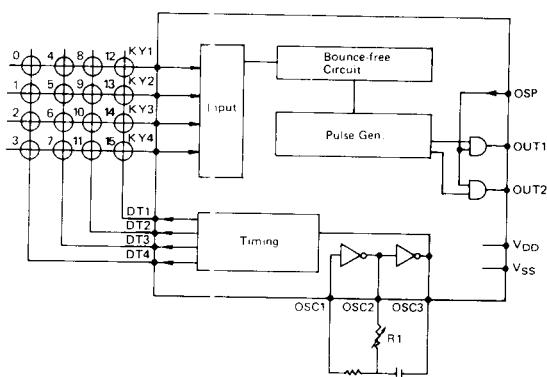
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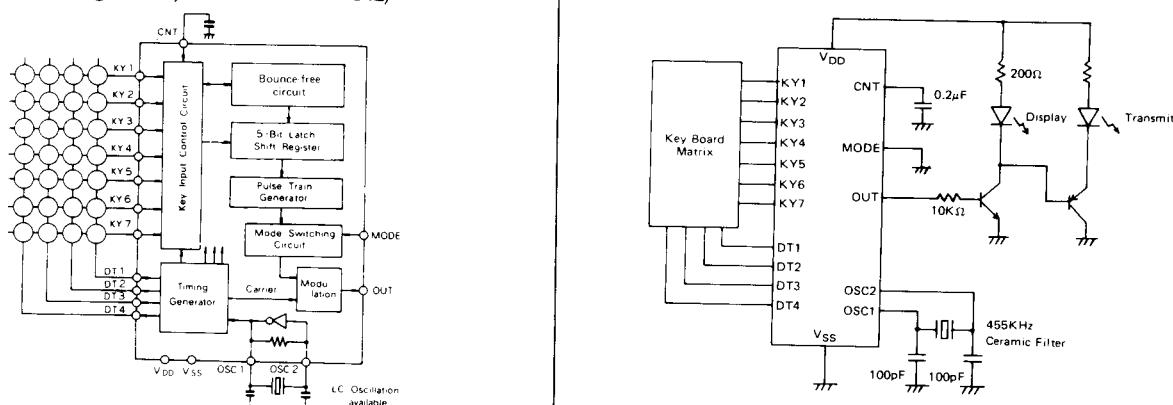
Block Diagram

Application Circuit

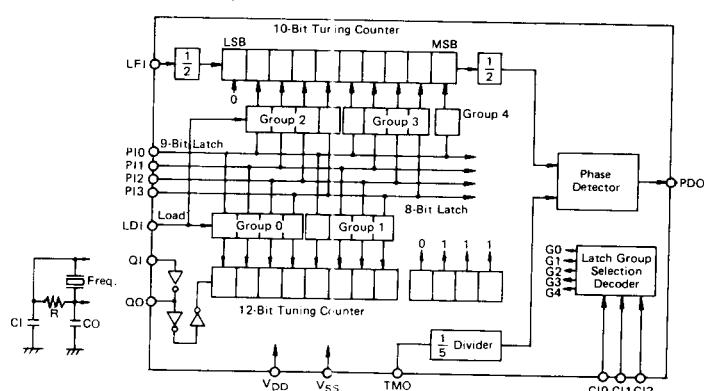
MN6024 (Package L-13,16-Lead Plastic DIL)



MN6025 (Package L-15,18-Lead Plastic DIL)



MN6044 (Package L-14,16-Lead Plastic DIL)



MN6047 (Package L-13,16-Lead Plastic DIL)

